# **Device Modeling Report**

COMPONENTS: MOSFET: OPERATIONAL AMPLIFIER

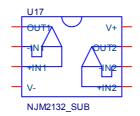
PART NUMBER:NJM2132

MANUFACTURER: NEW JAPAN RADIO CO.,LTD



**Bee Technologies Inc.** 

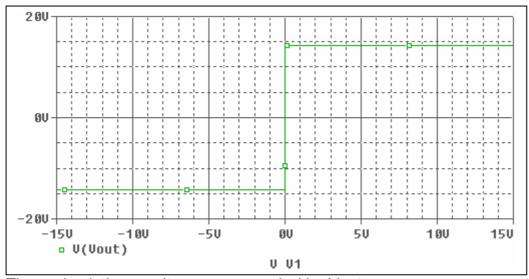
### **Spice Model**



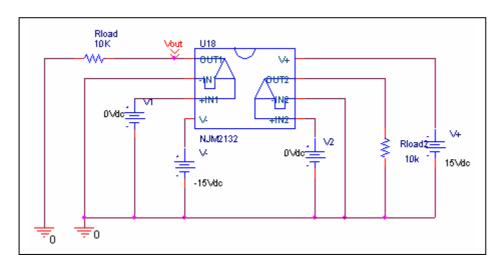
```
*$
* PART NUMBER:NJM2132
* MANUFACTURER: NEW JAPAN RADIO
* All Rights Reserved Copyright (c) Bee Technologies Inc. 2004
.Subckt NJM2132 OUT1 -IN1 +IN1 V- +IN2 -IN2 OUT2 V+
       +IN1 -IN1 V+ V- OUT1 NJM2132_SUB
X U2
       +IN2 -IN2 V+ V- OUT2 NJM2132_SUB
.ends NJM2132
*$
.subckt NJM2132_SUB 1 2 3 4 5
 c1 11 12 8.3716E-12
 c2 6 7 29.000E-12
 dc 5 53 dy
 de 54 5 dy
 dlp 90 91 dx
 dln 92 90 dx
 dp 4 3 dx
 egnd 99 0 poly(2) (3,0) (4,0) 0 .5 .5
 fb 7 99 poly(5) vb vc ve vlp vln 0 53.178E6 -1E3 1E3 53E6 -53E6
 ga 6 0 11 12 375.99E-6
 gcm 0 6 10 99 11.289E-9
 iee 3 10 dc 66.041E-6
 hlim 90 0 vlim 1K
 q1 11 2 13 qx1
 q2 12 1 14 qx2
 r2 6 9 100.00E3
 rc1 4 11 2.6526E3
 rc2 4 12 2.6526E3
 re1 13 10 1.8677E3
 re2 14 10 1.8677E3
 ree 10 99 3.0284E6
 ro1 8 5 50
 ro2 7 99 25
 rp 3 4 1.8072E3
 vb 9 0 dc 0
 vc 3 53 dc 1.5621
 ve 54 4 dc 1.5621
 vlim 7 8 dc 0
 vlp 91 0 dc 7.5000
 vln 0 92 dc 7.5000
.model dx D(Is=800.00E-18)
.model dy D(ls=800.00E-18 Rs=1m Cjo=10p)
.model qx1 PNP(ls=800.00E-18 Bf=1.3764E3)
.model qx2 PNP(Is=952.0300E-18 Bf=1.9614E3)
.ends
*$
```

# Output Voltage Swing, +Vout and -Vout

# Simulation result



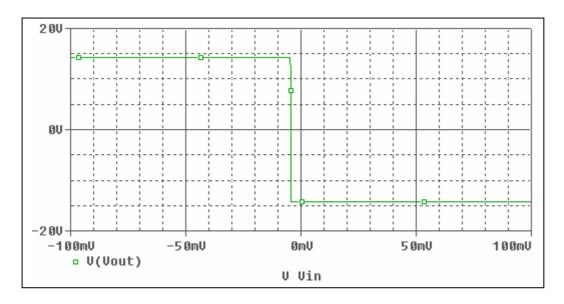
These simulation results are compared with <u>+</u>Vout

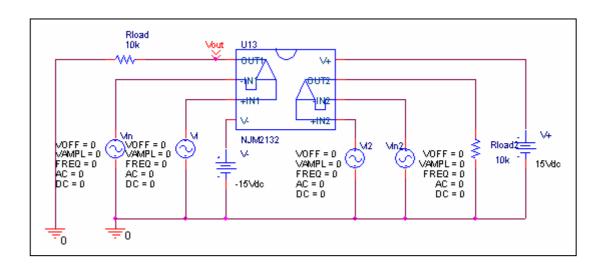


| Output Voltage Swing | Data sheet | Simulation | %Error |
|----------------------|------------|------------|--------|
| +Vout(V)             | +14.2      | 14.208     | 0.056  |
| -Vout(V)             | -14.2      | -14.208    | 0.056  |

# **Input Offset Voltage**

# Simulation result

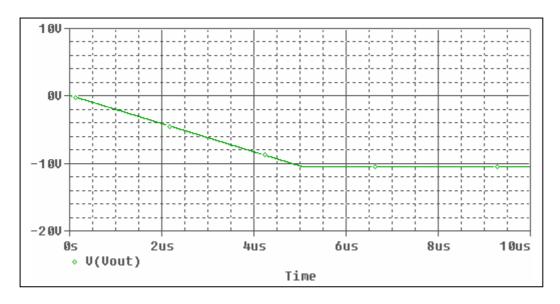


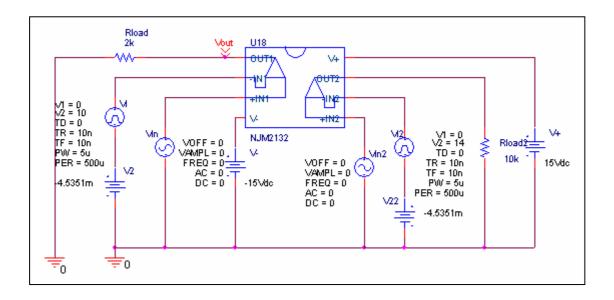


| Vos | Measurement |    | Simulation |    | Error |   |
|-----|-------------|----|------------|----|-------|---|
| Vos | 4.5         | mV | 4.5351     | mV | 0.78  | % |

## Slew Rate, +SR, -SR

### Simulation result

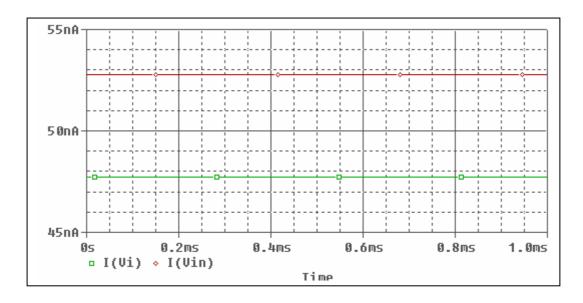


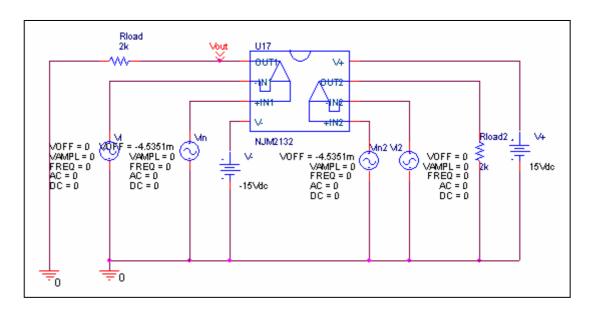


| Slew Rate(v/us) | Data sheet | Simulation | %Error |
|-----------------|------------|------------|--------|
| Siew Rate(vius) | 2.1V/us    | 2.2V/us    | 4.76   |

## Input current Ib, Ibos

### Simulation result

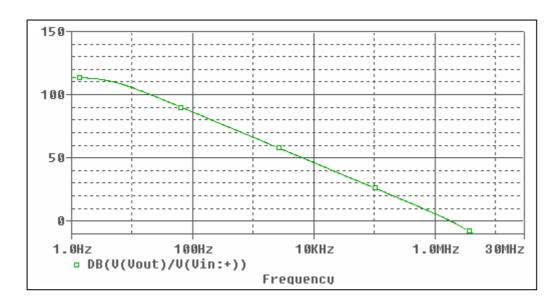


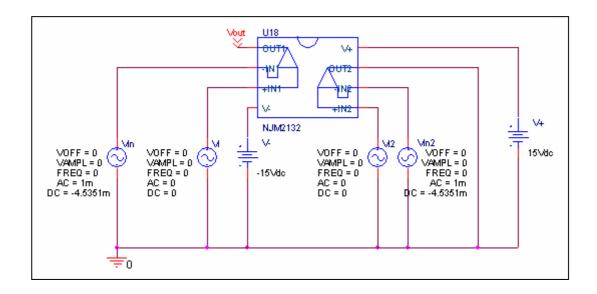


|          | Data sheet | Simulation | %Error |
|----------|------------|------------|--------|
| lb(nA)   | 20         | 20.1       | 0.5    |
| lbos(nA) | 5          | 5.02       | 0.4    |

# Open Loop Voltage Gain vs. Frequency, Av-dc, f-0dB

### Simulation result

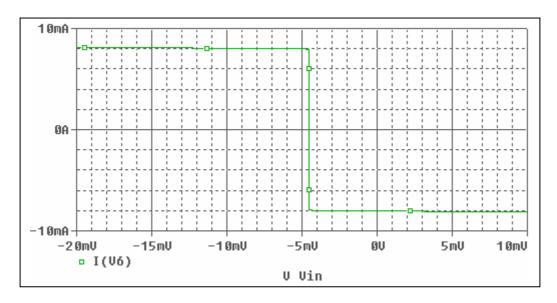


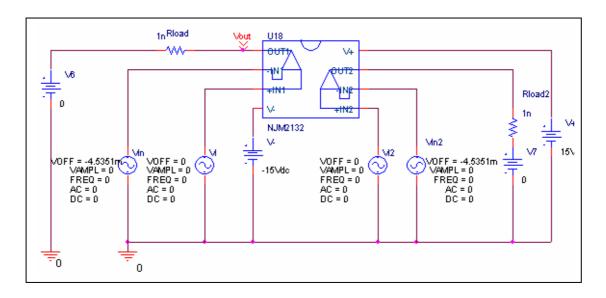


|            | Data sheet | Simulation | %Error |
|------------|------------|------------|--------|
| f-0dB(MHz) | 1.8        | 1.82       | 1.11   |
| Av-dc(dB)  | 114        | 113.8      | 0.175  |

## **Output Short Circuit Current - Ios**

# Simulation result

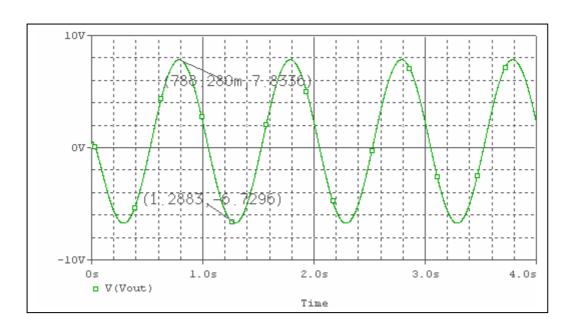


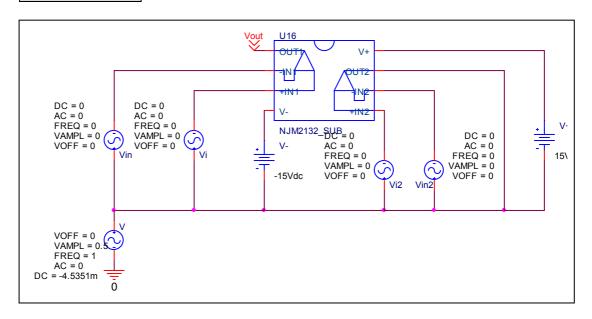


|                       | Data sheet | Simulation | %Error |
|-----------------------|------------|------------|--------|
| Short Circuit Current | 8mA        | 8.08mA     | 1      |

#### Common-Mode Rejection Voltage gain

#### Simulation result





Common mode gain=14.563/1 Common Mode Reject Ratio=489778/14.563=33631 = 90.5347dB

| _        | Data sheet | Simulation | %Error |
|----------|------------|------------|--------|
| CMRR(dB) | 90         | 90.5347    | 0.5941 |